

# SS22F THRU SS220F

Surface Mount Schottky Barrier Rectifier

Reverse Voltage - 20 to 200 V    Forward Current - 2.0A

## Features

- Metal silicon junction, majority carrier conduction
- For surface mounted applications
- Low power loss, high efficiency
- High forward surge current capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications

## MECHANICAL DATA

- Case: SMAF
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 27mg 0.00086oz

## Absolute Maximum Ratings and Electrical characteristics

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz resistive or inductive load, for capacitive load, derate by 20 %

PINNING	
PIN	DESCRIPTION
1	Cathode
2	Anode



Parameter	Symbols	SS22F	SS24F	SS26F	SS28F	SS210F	SS212F	SS215F	SS220F	Units		
Maximum Repetitive Peak Reverse Voltage	$V_{RRM}$	20	40	60	80	100	120	150	200	V		
Maximum RMS voltage	$V_{RMS}$	14	28	42	56	70	84	105	140	V		
Maximum DC Blocking Voltage	$V_{DC}$	20	40	60	80	100	120	150	200	V		
Maximum Average Forward Rectified Current	$I_{F(AV)}$	2.0							A			
Peak Forward Surge Current, 8.3ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	$I_{FSM}$	50				40				A		
Max Instantaneous Forward Voltage at 2A	$V_F$	0.55		0.70		0.85		0.95		V		
Maximum DC Reverse Current $T_a = 25^\circ C$ at Rated DC Reverse Voltage $T_a = 100^\circ C$	$I_R$	0.5 10		0.3 5						mA		
Typical Junction Capacitance <sup>1)</sup>	$C_J$	220		80						pF		
Operating Junction Temperature Range	$T_j$	-55 ~ +125							$^\circ C$			
Storage Temperature Range	$T_{stg}$	-55 ~ +150							$^\circ C$			

1) Measured at 1MHz and applied reverse voltage of 4 V D.C.

SHIKE MAKE CONSCIOUS PRODUCT

CONSCIOUS PRODUCTS BEGIN WITH CONSCIOUS PEOPLE



# SS22F THRU SS220F

Fig.1 Forward Current Derating Curve

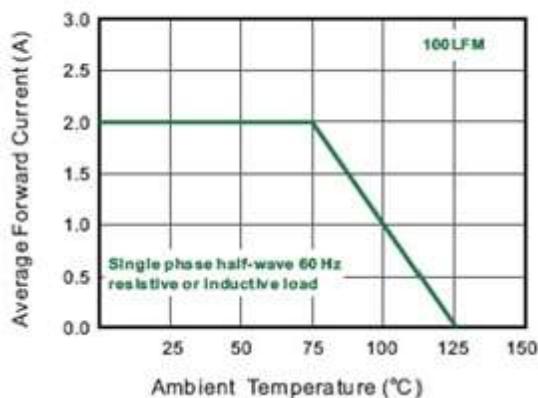


Fig.2 Typical Reverse Characteristics

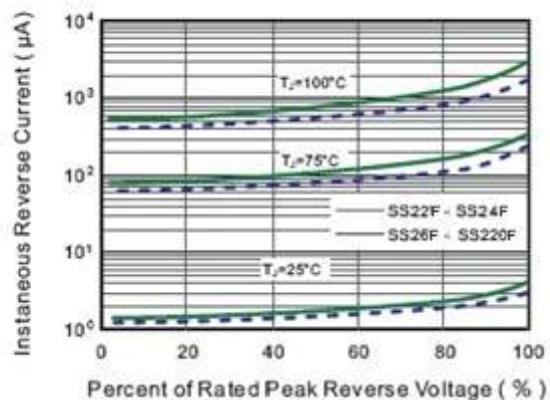


Fig.3 Typical Forward Characteristic

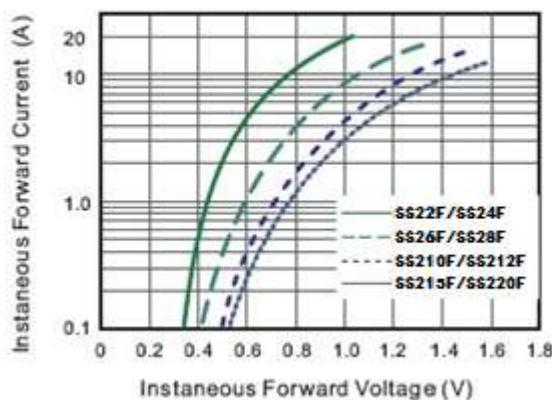


Fig.4 Typical Junction Capacitance

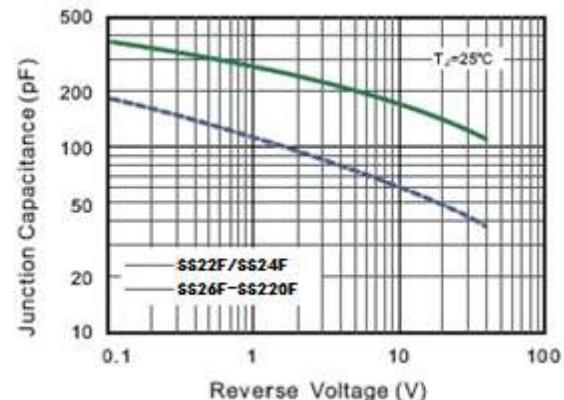
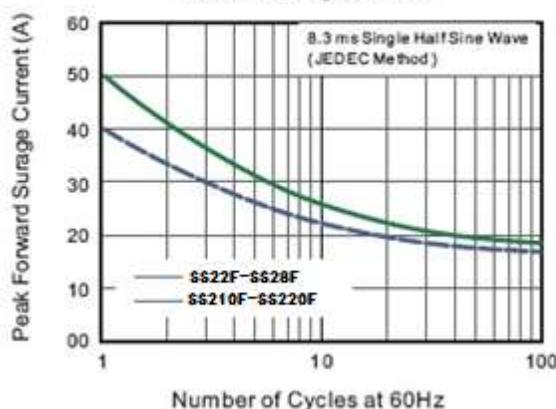


Fig.5 Maximum Non-Repetitive Peak Forward Surge Current

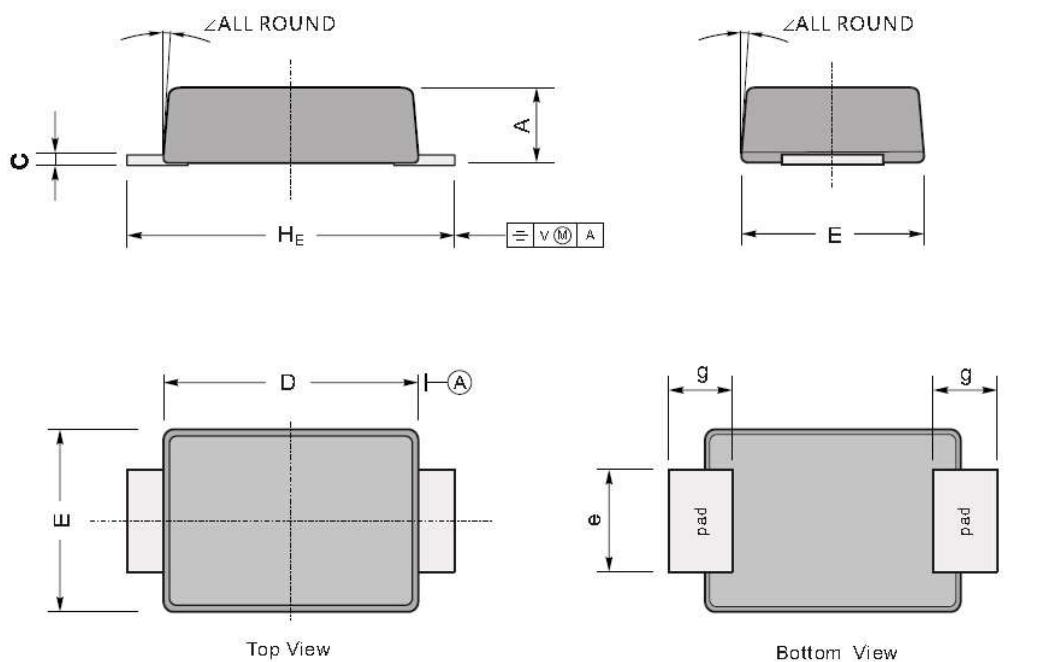


SHIKE MAKE CONSCIOUS PRODUCT  
CONSCIOUS PRODUCTS BEGIN WITH CONSCIOUS PEOPLE



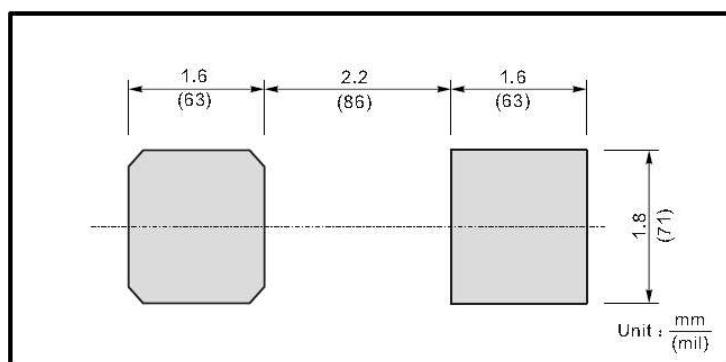
## PACKAGE OUTLINE

Plastic surface mounted package; 2 leads



UNIT		A	C	D	E	e	g	$H_E$	$\angle$
mm	max	1.1	0.20	3.7	2.7	1.6	1.2	4.9	$7^\circ$
	min	0.9	0.12	3.3	2.4	1.3	0.8	4.4	
mil	max	43	7.9	146	106	63	47	193	$7^\circ$
	min	35	4.7	130	94	51	31	173	

## The recommended mounting pad size



SHIKE MAKE CONSCIOUS PRODUCT

CONSCIOUS PRODUCTS BEGIN WITH CONSCIOUS PEOPLE

# X-ON Electronics

Largest Supplier of Electrical and Electronic Components

***Click to view similar products for Schottky Diodes & Rectifiers category:***

***Click to view products by Shikues manufacturer:***

Other Similar products are found below :

[MA4E2039](#) [MA4E2508M-1112](#) [MBR10100CT-BP](#) [MBR1545CT](#) [MMBD301M3T5G](#) [GS1JE-TP](#) [RB160M-50TR](#) [BAS 3010S-02LRH E6327](#)  
[BAT 54-02LRH E6327](#) [NSR05F40QNXT5G](#) [NSVR05F40NXT5G](#) [NTE555](#) [JANS1N6640](#) [SB07-03C-TB-H](#) [SB1003M3-TL-W](#)  
[SBAT54CWT1G](#) [SBM30-03-TR-E](#) [SK310-T](#) [SK33A-TP](#) [SK34B-TP](#) [SS3003CH-TL-E](#) [PDS3100Q-7](#) [GA01SHT18](#) [CRS10I30A\(TE85L,QM\)](#)  
[MA4E2501L-1290](#) [MBRB30H30CT-1G](#) [BAS 70-02L E6327](#) [DMJ3940-000](#) [SB007-03C-TB-E](#) [SB10015M-TL-E](#) [SB1003M3-TL-E](#) [SK32A-](#)  
[TP](#) [SK33B-TP](#) [SK35A-TP](#) [SK38B-LTP](#) [SK38B-TP](#) [NTE505](#) [NTSB30U100CT-1G](#) [VS-6CWQ10FNHM3](#) [CRG04\(T5L,TEMQ\)](#)  
[ACDBA1100LR-HF](#) [ACDBA1200-HF](#) [ACDBA140-HF](#) [ACDBA2100-HF](#) [ACDBA240-HF](#) [ACDBA3100-HF](#) [CDBQC0530L-HF](#) [BAT54-](#)  
[13-F](#) [ACDBA340-HF](#) [ACDBA260LR-HF](#)